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Team Nexperia

# 74HC4040; 74HCT4040 12-stage binary ripple counter Rev. 5 — 3 February 2016

**Product data sheet** 

# **General description**

The 74HC4040; 74HCT4040 is a 12-stage binary ripple counter with a clock input (CP), an overriding asynchronous master reset input (MR) and twelve parallel outputs (Q0 to Q11). The counter advances on the HIGH-to-LOW transition of CP. A HIGH on MR clears all counter stages and forces all outputs LOW, independent of the state of CP. Each counter stage is a static toggle flip-flop. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of V<sub>CC</sub>.

#### **Features and benefits** 2.

- Complies with JEDEC standard no. 7A
- Input levels:
  - For 74HC4040: CMOS level
  - ◆ For 74HCT4040: TTL level
- ESD protection:
  - ♦ HBM JESD22-A114F exceeds 2000 V
  - ♦ MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

# **Applications**

- Frequency dividing circuits
- Time delay circuits
- Control counters

# **Ordering information**

Table 1. **Ordering information** 

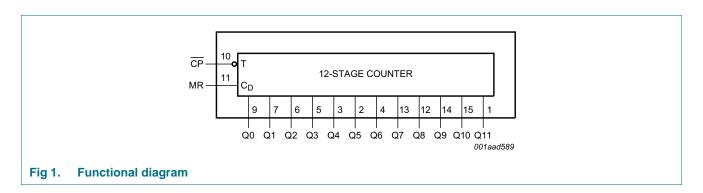
Type number	Package									
	Temperature range	Name	Description	Version						
74HC4040D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body	SOT109-1						
74HCT4040D			width 3.9 mm							
74HC4040DB	–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body	SOT338-1						
74HCT4040DB			width 5.3 mm							

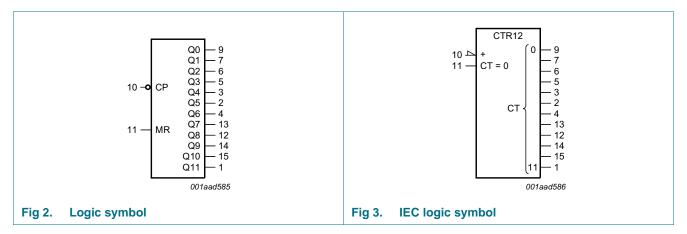


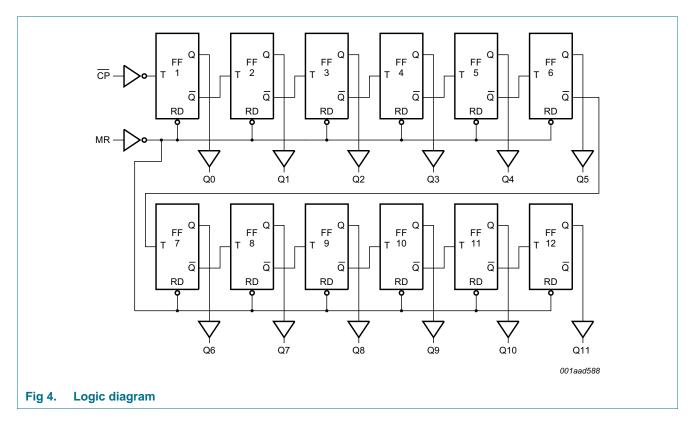
 Table 1.
 Ordering information ...continued

Type number	Package								
	Temperature range	Name	Description	Version					
74HC4040PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1					
74HCT4040PW			body width 4.4 mm						
74HC4040BQ	–40 °C to +125 °C	DHVQFN16		SOT763-1					
74HCT4040BQ			very thin quad flat package; no leads; 16 terminals; body $2.5 \times 3.5 \times 0.85$ mm						

# 5. Functional diagram

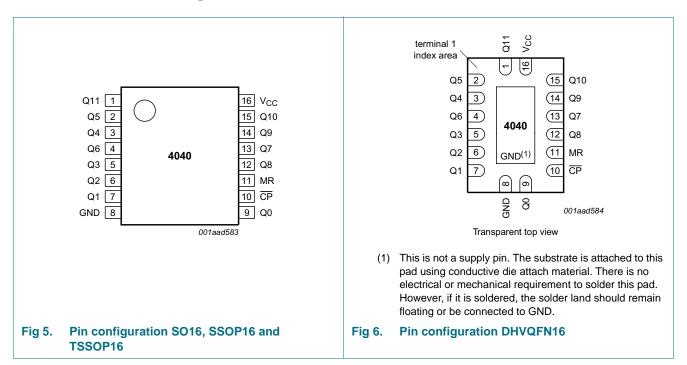






# 6. Pinning information

## 6.1 Pinning



## 6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
Q11	1	output 11
Q5	2	output 5
Q4	3	output 4
Q6	4	output 6
Q3	5	output 3
Q2	6	output 2
Q1	7	output 1
GND	8	ground (0 V)
Q0	9	output 0
CP	10	clock input (HIGH-to-LOW, edge-triggered)
MR	11	master reset input (active HIGH)
Q8	12	output 8
Q7	13	output 7
Q9	14	output 9
Q10	15	output 10
V <sub>CC</sub>	16	positive supply voltage

# 7. Functional description

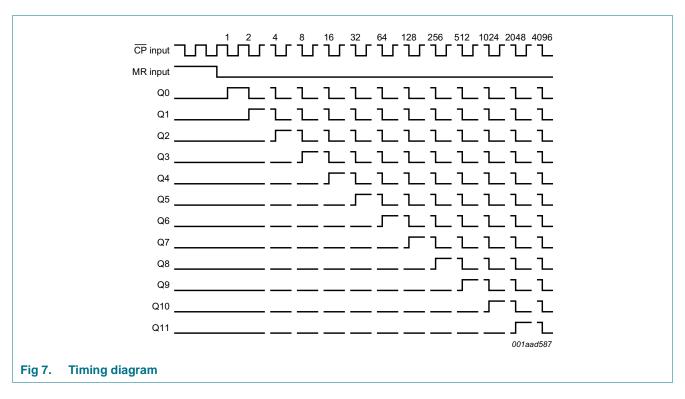
## 7.1 Function table

Table 3. Function table

Input		Output		
CP	MR	Q0 to Q11		
$\uparrow$	L	no change		
$\downarrow$	L	count		
X	Н	L		

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care;  $\uparrow = LOW \text{-to-HIGH clock transition}$ ;  $\downarrow = HIGH \text{-to-LOW clock transition}$ .

## 7.2 Timing diagram



## **Limiting values**

Table 4. **Limiting values** 

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{CC}$	supply voltage			-0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 \text{ V or VI} > V_{CC} + 0.5 \text{ V}$	<u>[1]</u>	-	±20	mA
I <sub>OK</sub>	output clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	<u>[1]</u>	-	±20	mA
Io	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$		-	±25	mA
I <sub>CC</sub>	supply current			-	±50	mA
I <sub>GND</sub>	ground current			-	±50	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$	[2]			
		SO16, SSOP16, TSSOP16 and DHVQFN16 packages		-	500	mW

- [1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
- [2] For SO16 package:  $P_{tot}$  derates linearly with 8 mW/K above 70 °C. For SSOP16 and TSSOP16 packages: Ptot derates linearly with 5.5 mW/K above 60 °C. For DHVQFN16 packages: Ptot derates linearly with 4.5 mW/K above 60 °C.

# **Recommended operating conditions**

**Recommended operating conditions** 

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	7	74HC4040			74HCT4040		
			Min	Тур	Max	Min	Тур	Max	
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 2.0 \text{ V}$	-	-	625	-	-	-	ns/V
		V <sub>CC</sub> = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}$	-	-	83	-	-	-	ns/V

## 10. Static characteristics

#### **Static characteristics** Table 6.

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	-40 °C to	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC40	40									
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V <sub>CC</sub> = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	$I_{O} = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_{O} = -20 \mu A$ ; $V_{CC} = 4.5 \text{ V}$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -20 \mu A; V_{CC} = 6.0 V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	3.84	-	3.7	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	5.34	-	5.2	-	V
V <sub>OL</sub>	LOW-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	$I_O = 20 \mu A; V_{CC} = 2.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 6.0 \text{ V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V
		$I_O = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	-	80	-	160	μΑ

Table 6. Static characteristics ... continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
C <sub>I</sub>	input capacitance		-	3.5	-					pF
74HCT4	040								•	,
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
$V_{IL}$	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	1.2	8.0	-	0.8	-	0.8	V
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_{O} = -20 \mu A$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -4 \text{ mA}$	3.98	4.32	-	3.84	-	3.7	-	V
$V_{OL}$	LOW-level	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = 20 μA	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 4.0 \text{ mA}$	-	0.15	0.26	-	0.33	-	0.4	V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μА
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
Δl <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V; } I_O = 0 \text{ A;}$ other inputs at $V_{CC}$ or GND; $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$								
		pin CP	-	85	306	-	383	-	417	μΑ
		pin MR	-	110	396	-	495	-	539	μΑ
C <sub>I</sub>	input capacitance		-	3.5	-	-	-	-	-	pF

# 11. Dynamic characteristics

Table 7. Dynamic characteristics

GND (ground = 0 V);  $C_L = 50$  pF unless otherwise specified; for test circuit, see Figure 9.

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC404	10									
t <sub>pd</sub>	propagation	CP to Q0; see Figure 8 [1]								
	delay	V <sub>CC</sub> = 2.0 V	-	47	150	-	190	-	225	ns
		V <sub>CC</sub> = 4.5 V	-	17	30	-	38	-	45	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$	-	14	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	14	26	-	33	-	38	ns
		Qn to Qn+1; see Figure 8								
		V <sub>CC</sub> = 2.0 V	-	28	100	-	125	-	150	ns
		V <sub>CC</sub> = 4.5 V	-	10	20	-	25	-	30	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	8	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V		8	17	-	21	-	26	ns
t <sub>PHL</sub>	HIGH to LOW	MR to Qn; see Figure 8								
	propagation	V <sub>CC</sub> = 2.0 V	-	61	185	-	230	-	280	ns
	delay	V <sub>CC</sub> = 4.5 V	-	22	37	-	46	-	56	ns
		V <sub>CC</sub> = 6.0 V	-	18	31	-	39	-	48	ns
t <sub>t</sub>	transition time	Qn; see Figure 8								
		V <sub>CC</sub> = 2.0 V	-	19	75	-	95	-	110	ns
		V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
		V <sub>CC</sub> = 6.0 V	-	6	13	-	16	-	19	ns
t <sub>W</sub>	pulse width	CP input, HIGH or LOW; see Figure 8								
		V <sub>CC</sub> = 2.0 V	80	14	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	5	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	4	-	17	-	20	-	ns
		MR input, HIGH; see Figure 8								
		V <sub>CC</sub> = 2.0 V	80	22	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	8	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	6	-	17	-	20	-	ns
t <sub>rec</sub>	recovery time	MR to CP; see Figure 8								
		V <sub>CC</sub> = 2.0 V	50	8	-	65	-	75	-	ns
		V <sub>CC</sub> = 4.5 V	10	3	-	13	-	15	-	ns
		V <sub>CC</sub> = 6.0 V	9	2	-	11	-	13	-	ns
f <sub>max</sub>	maximum	CP input; see Figure 8								
	frequency	V <sub>CC</sub> = 2.0 V	6	27	-	4.8	-	4	-	MHz
		V <sub>CC</sub> = 4.5 V	30	82	-	24	-	20	-	MHz
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	90	-	-	-	-	-	MHz
		V <sub>CC</sub> = 6.0 V	35	98	-	28	-	24	-	MHz

74HC\_HCT4040

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Table 7. Dynamic characteristics ...continued

GND (ground = 0 V); C<sub>L</sub> = 50 pF unless otherwise specified; for test circuit, see Figure 9.

Symbol	Parameter	Conditions		25 °C	;	–40 °C t	o +85 °C	-40 °C to	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
C <sub>PD</sub>	power dissipation capacitance	$V_I = GND \text{ to } V_{CC}$ [3]	-	20	-	-	-	-	-	pF
74HCT40	)40				•	,				
t <sub>pd</sub>	propagation	CP to Q0; see Figure 8 [1]								
	delay	V <sub>CC</sub> = 4.5 V	-	19	40	-	50	-	60	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$	-	16	-	-	-	-	-	ns
		Qn to Qn+1; see Figure 8								
		V <sub>CC</sub> = 4.5 V	-	10	20	-	25	-	30	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF		8	-	-	-	-	-	ns
t <sub>PHL</sub> HIGH to LOW		MR to Qn; see Figure 8								
	propagation delay	V <sub>CC</sub> = 4.5 V	-	23	45	-	56	-	68	ns
t <sub>t</sub> transition	transition time	Qn; see Figure 8 [2]								
		V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
t <sub>W</sub>	pulse width	CP input, HIGH or LOW; see Figure 8								
		V <sub>CC</sub> = 4.5 V	16	7	-	20	-	24	-	ns
		MR input, HIGH; see Figure 8								
		V <sub>CC</sub> = 4.5 V	16	6	-	20	-	24	-	ns
t <sub>rec</sub>	recovery time	MR to CP; see Figure 8								
		V <sub>CC</sub> = 4.5 V	10	2	-	13	-	15	-	ns
f <sub>max</sub>	maximum	CP input; see Figure 8								
	frequency	V <sub>CC</sub> = 4.5 V	30	72	-	24	-	20	-	MHz
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$	-	79	-	-	-	-	-	MHz
C <sub>PD</sub>	power dissipation capacitance	$V_I = GND \text{ to } V_{CC}$ [3]	-	20	-	-	-	-	-	pF

<sup>[1]</sup>  $t_{pd}$  is the same as  $t_{PHL}$ ,  $t_{PLH}$ .

[3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

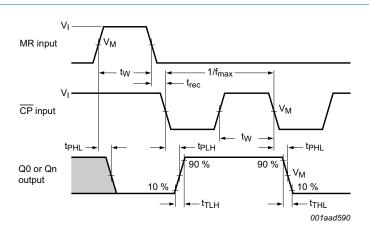
V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

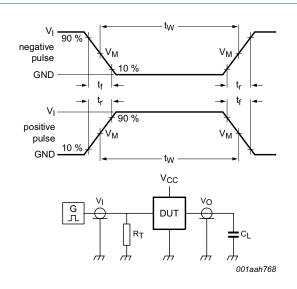
<sup>[2]</sup>  $t_t$  is the same as  $t_{THL}$ ,  $t_{TLH}$ .

## 12. Waveform and test circuit



74HC4040:  $V_M = 50$  %;  $V_I = GND$  to  $V_{CC}$ . 74HCT4040:  $V_M = 1.3$  V;  $V_I = GND$  to 3 V.

Fig 8. Clock propagation delays, pulse width, transition times, maximum pulse frequency and master resets



Test data is given in Table 8.

Definitions test circuit:

 $R_T$  = termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

 $C_L$  = load capacitance including jig and probe capacitance.

Fig 9. Test circuit for measuring switching times

Table 8. Test data

Туре	Input L		Load	
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	
74HC4040	V <sub>CC</sub>	6.0 ns	15 pF, 50 pF	t <sub>PLH</sub> , t <sub>PHL</sub>
74HCT4040	3.0 V	6.0 ns	15 pF, 50 pF	t <sub>PLH</sub> , t <sub>PHL</sub>

74HC\_HCT4040

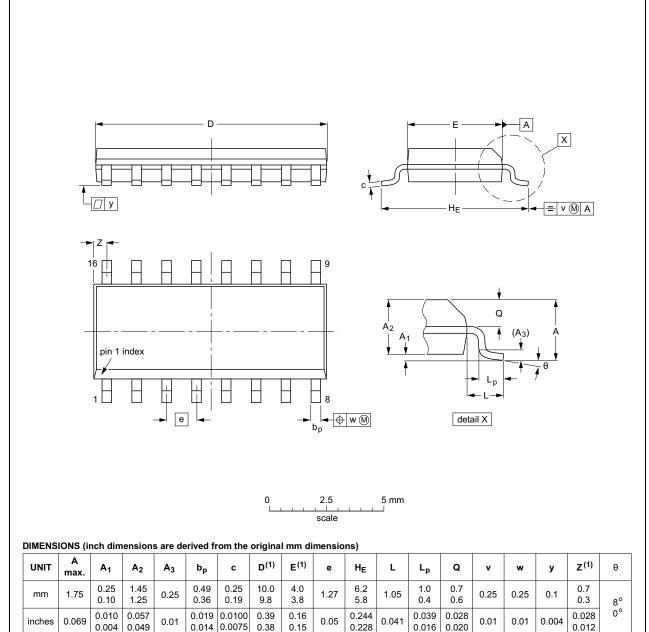
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# 13. Package outline

## SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



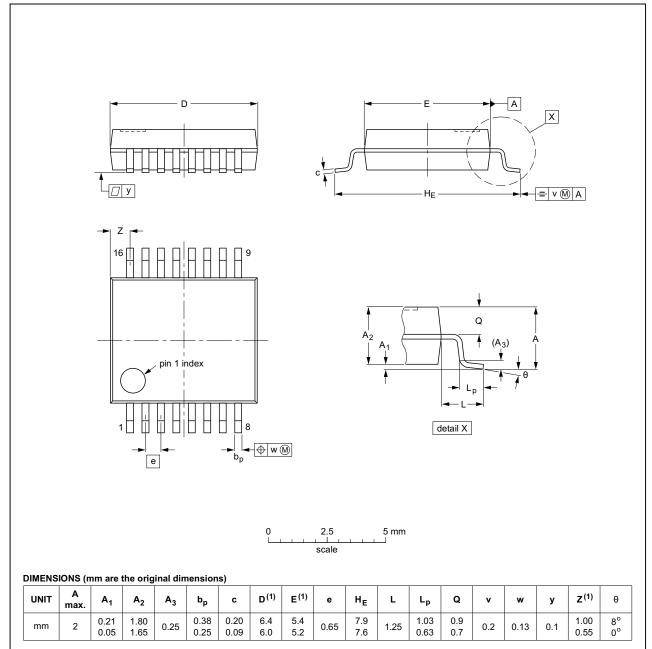
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012				<del>99-12-27</del> 03-02-19	

Fig 10. Package outline SOT109-1 (SO16)

## SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



## Note

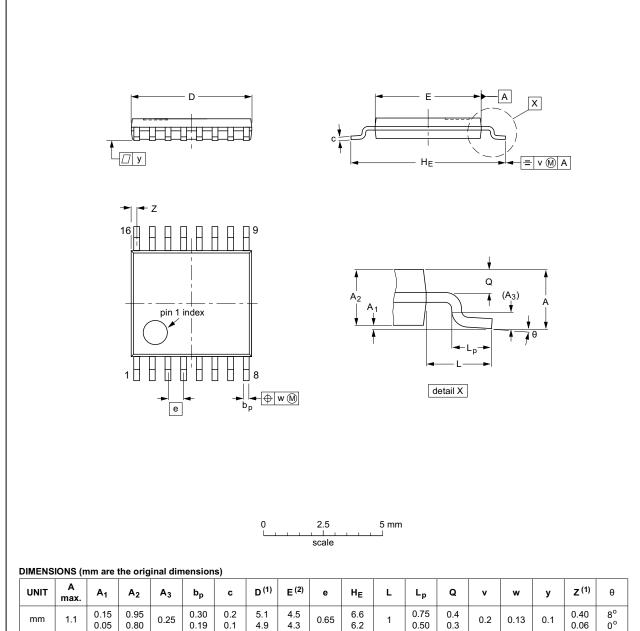
1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT338-1		MO-150				<del>99-12-27</del> 03-02-19	

Fig 11. Package outline SOT338-1 (SSOP16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	<b>A</b> <sub>3</sub>	bp	C	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

## Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT403-1		MO-153				<del>99-12-27</del> 03-02-18

Fig 12. Package outline SOT403-1 (TSSOP16)

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

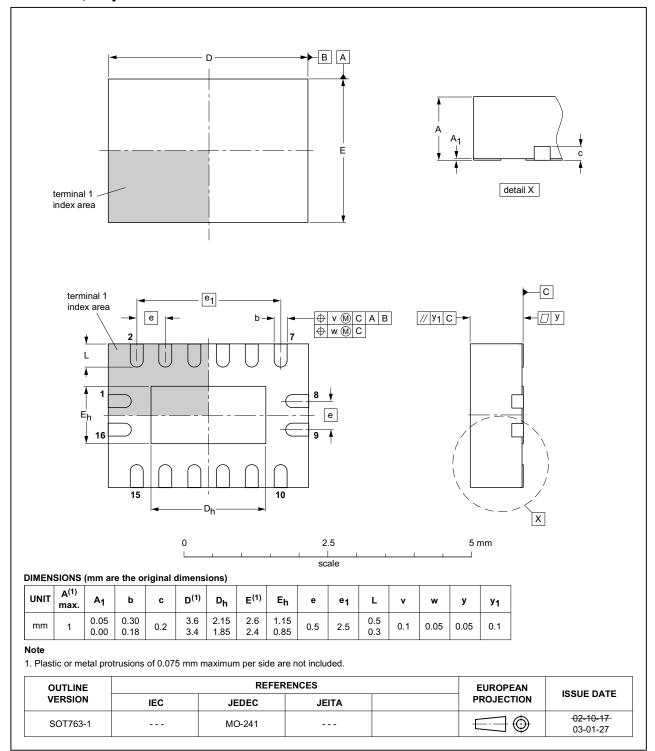


Fig 13. Package outline SOT763-1 (DHVQFN16)

## 14. Abbreviations

## Table 9. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
ESD	ElectroStatic Discharge
НВМ	Human Body Model
CDM	Charge-Device Model
TTL	Transistor-Transistor Logic

# 15. Revision history

## Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT4040 v.5	20160203	Product data sheet	-	74HC_HCT4040 v.4
Modifications:	Type numbers 74H	C4040N and 74HCT404	ION (SOT38-4) rei	moved.
74HC_HCT4040 v.4	20140320	Product data sheet	-	74HC_HCT4040 v.3
Modifications:	The format of this of guidelines of NXP s	lata sheet has been rede Semiconductors.	esigned to comply	with the new identity
	<ul> <li>Legal texts have be</li> </ul>	een adapted to the new	company name wl	here appropriate.
74HC_HCT4040 v.3	20050914	Product data sheet	-	74HC_HCT4040_CNV v.2
74HC_HCT4040_CNV v.2	19901231	Product specification	-	-

# 16. Legal information

## 16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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## 12-stage binary ripple counter

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